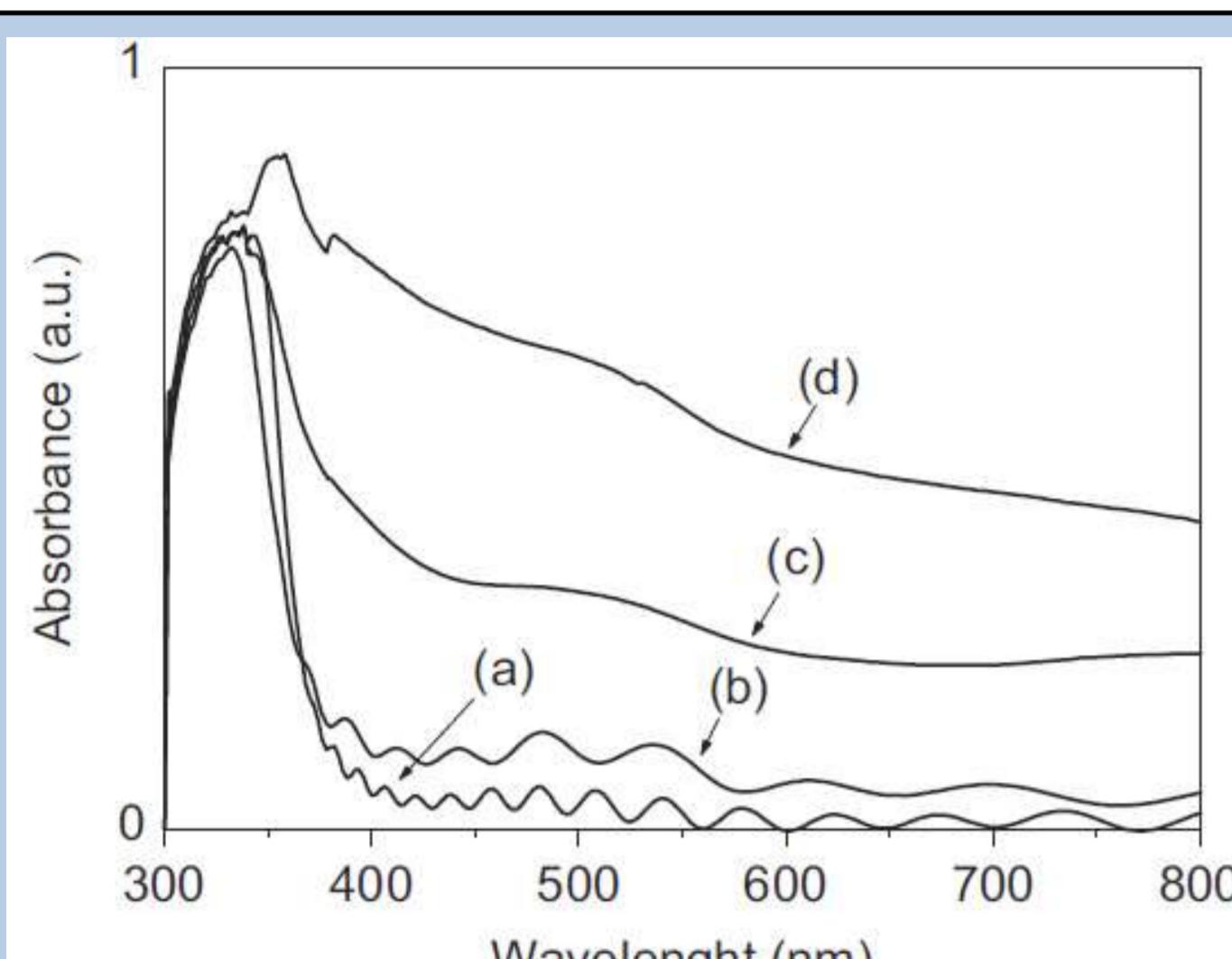


## Background

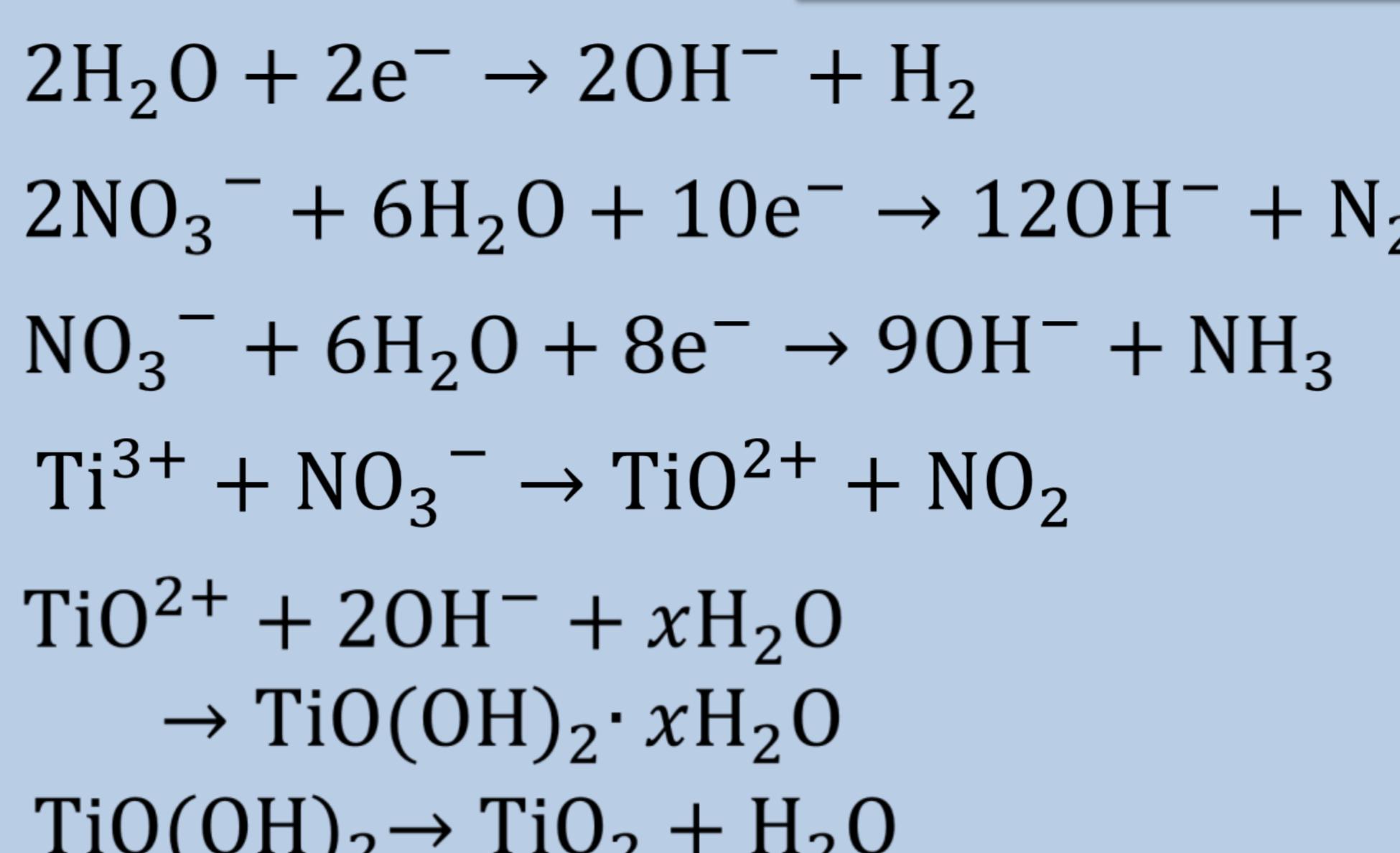
### Applications of TiO<sub>2</sub> Micro-Structures

- Light-extraction enhancement in GaInN light-emitting diodes<sup>1</sup>
- Enhancement of I-V characteristics and efficiency for dye-sensitized solar cell<sup>2</sup>

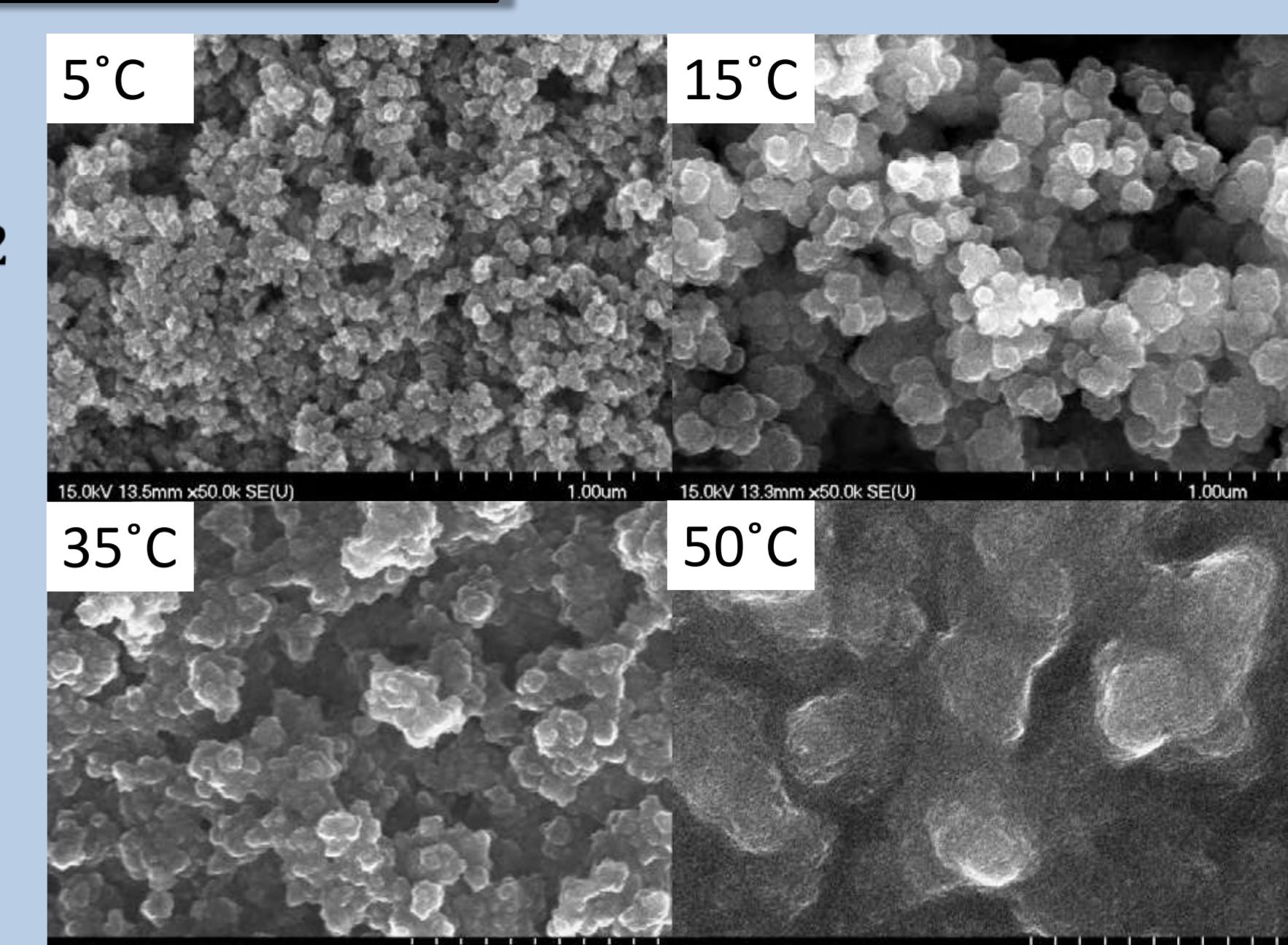


UV-vis absorption spectra of (a) TiO<sub>2</sub> film, (b) TiO<sub>2</sub> micro-structures, (c) TiO<sub>2</sub> film with N3 dye adsorbed, and (d) TiO<sub>2</sub> micro-structures with N3 dye adsorbed<sup>2</sup>

### Cathodic Deposition of TiO<sub>2</sub>



- Offers a low-cost yet effective process for production of TiO<sub>2</sub>



- Morphology control by different experimental temperature<sup>3</sup>

## Experimental Section

Conductive substrate  
SU-8 layer  
TiO<sub>2</sub>  
1X2 cm<sup>2</sup> Cu plate

- 1. Pretreatment of the substrate**
- 10 wt% Ace Clean solution for 1 min
  - 10 wt% HCl solution for 10 sec

### Fabrication procedures

- 6. TiO<sub>2</sub> micro-structures obtained after removal of SU-8 patterns**
- Remover PG
  - 80 °C for 10 min

### 2. Coat the SU-8 photoresist layer

- Pre-bake at 60 °C for 10 min
- Softbake at 80 °C for 5 min

### 3. Exposure at 400 mJ/cm<sup>2</sup>

- Post expose bake 1 at 65 °C for 3 min
- Post expose bake 1 at 95 °C for 6 min

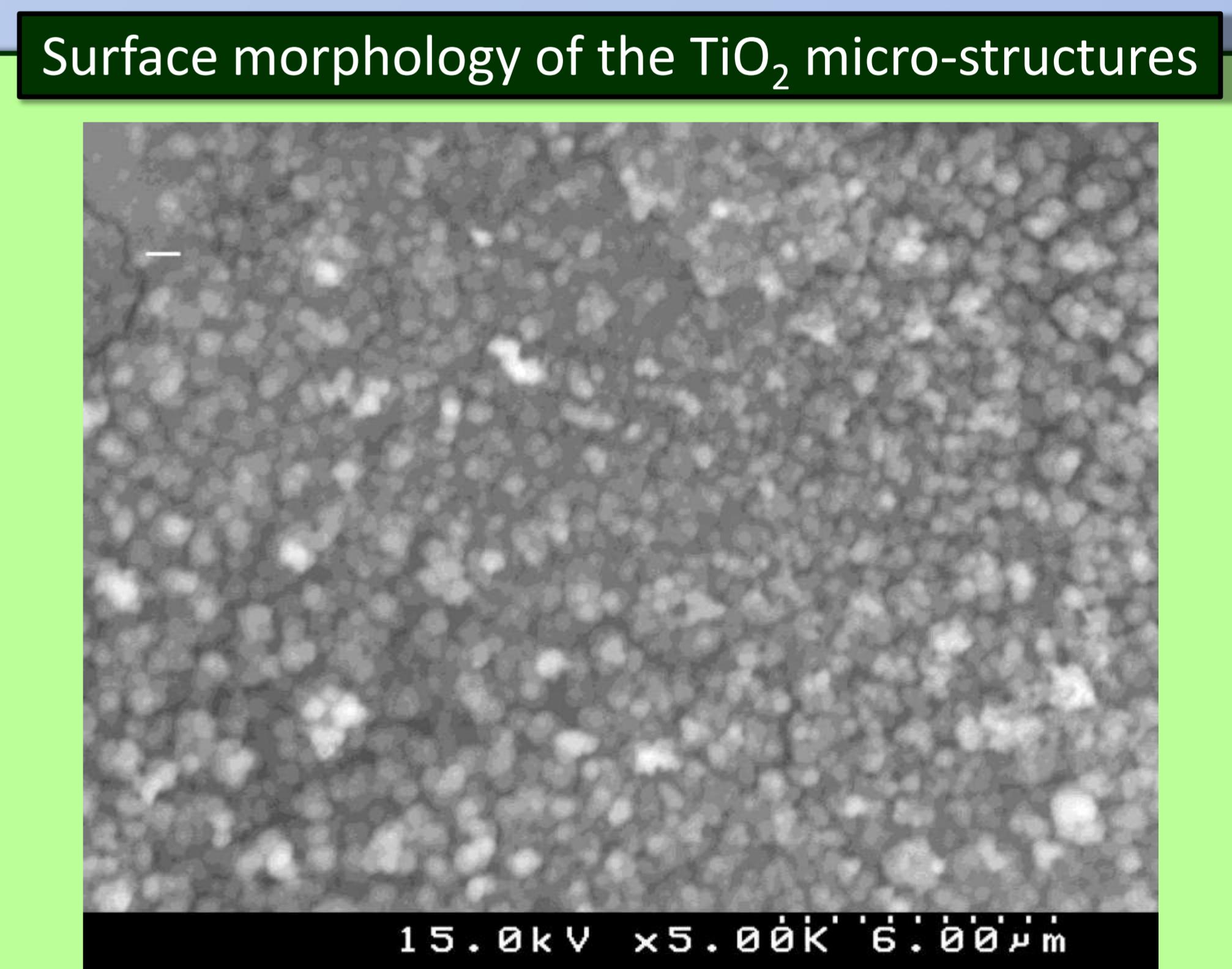
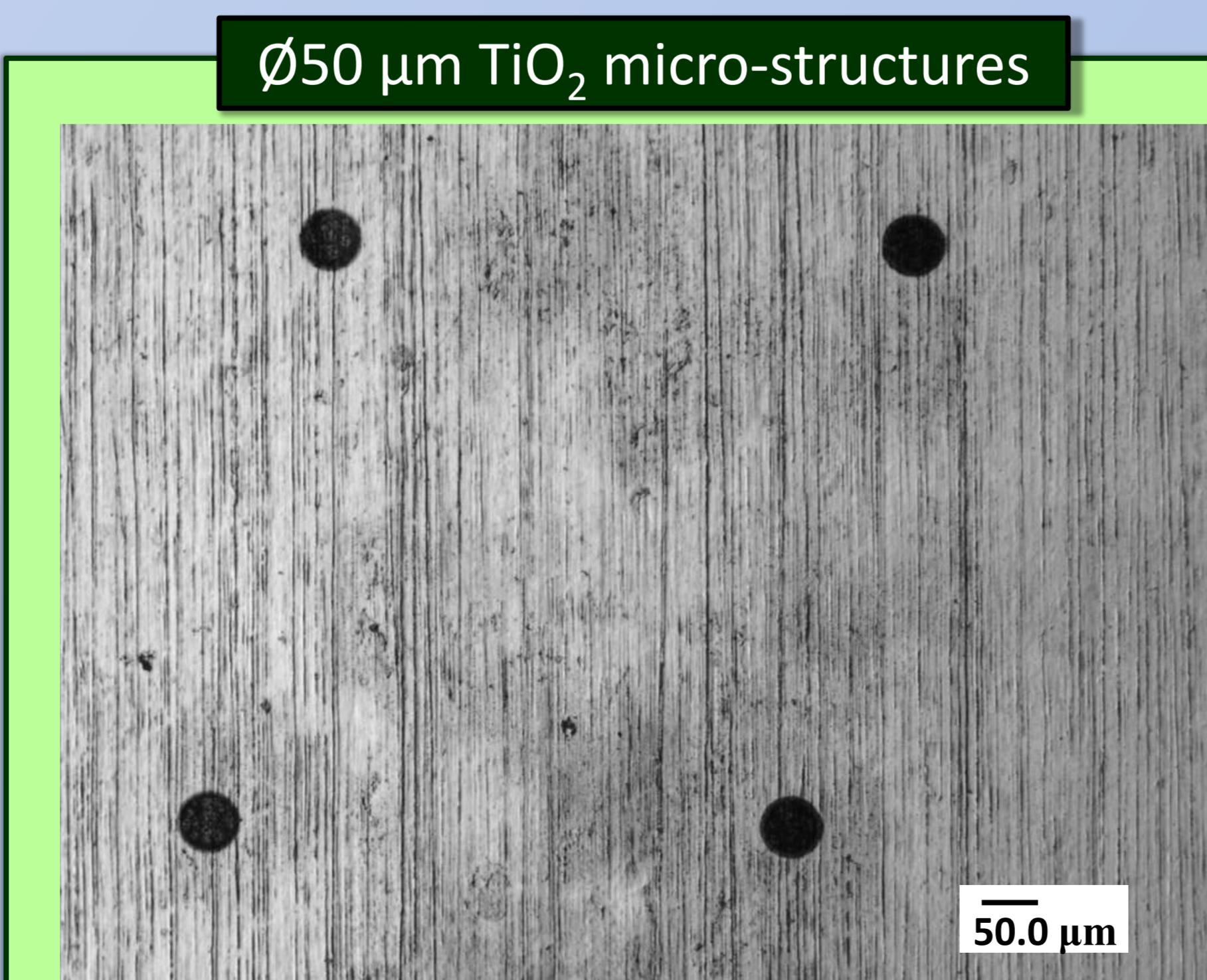
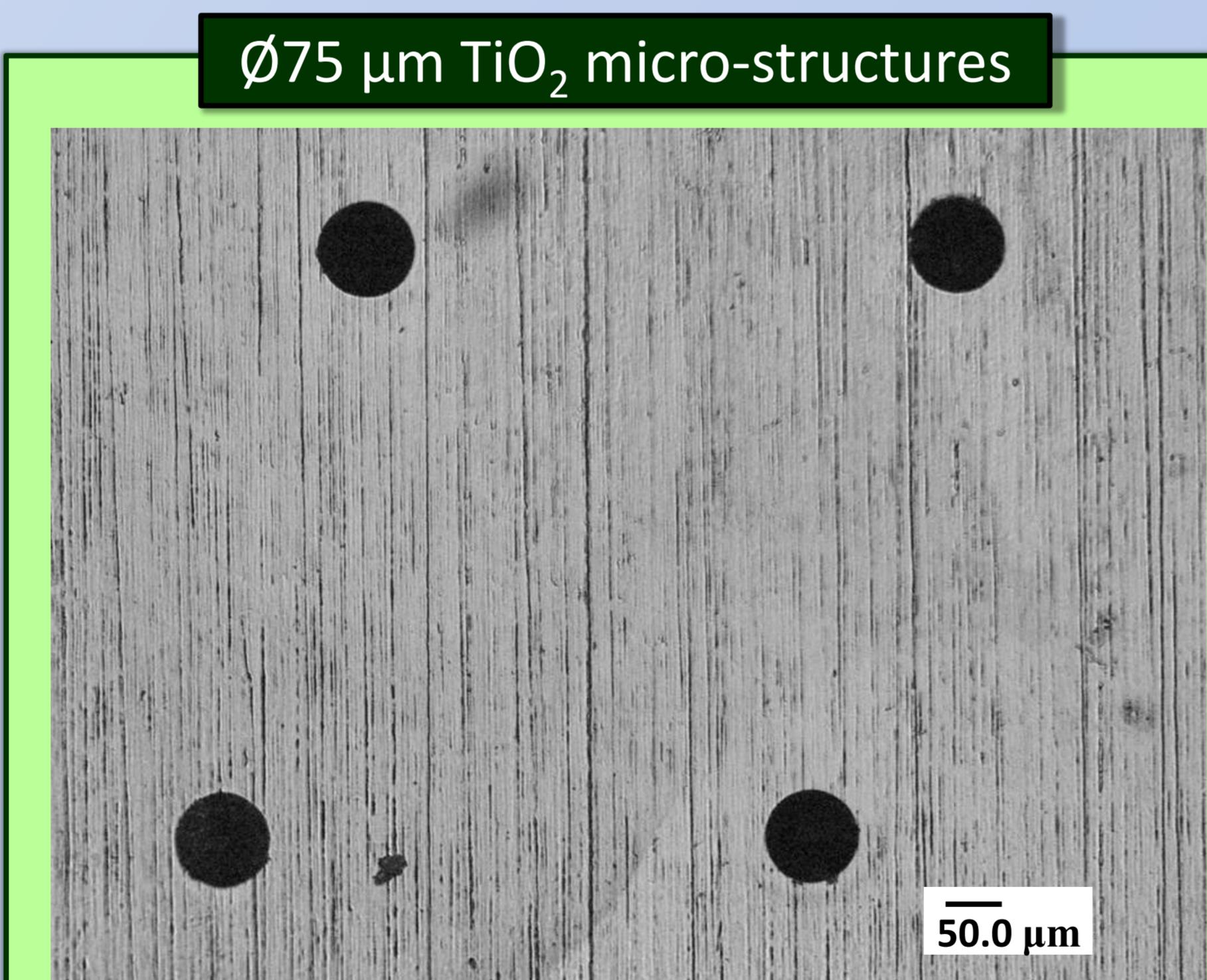
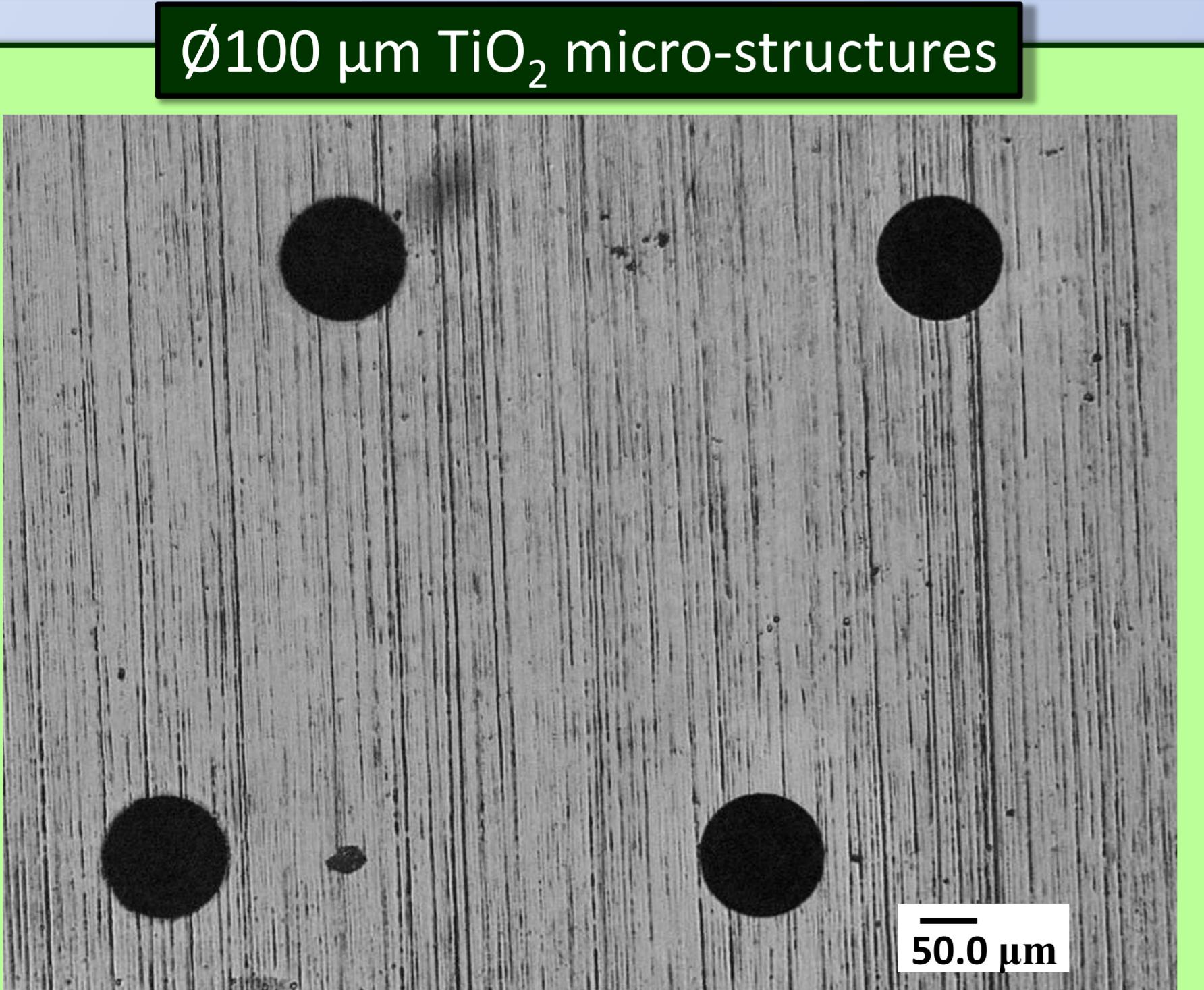
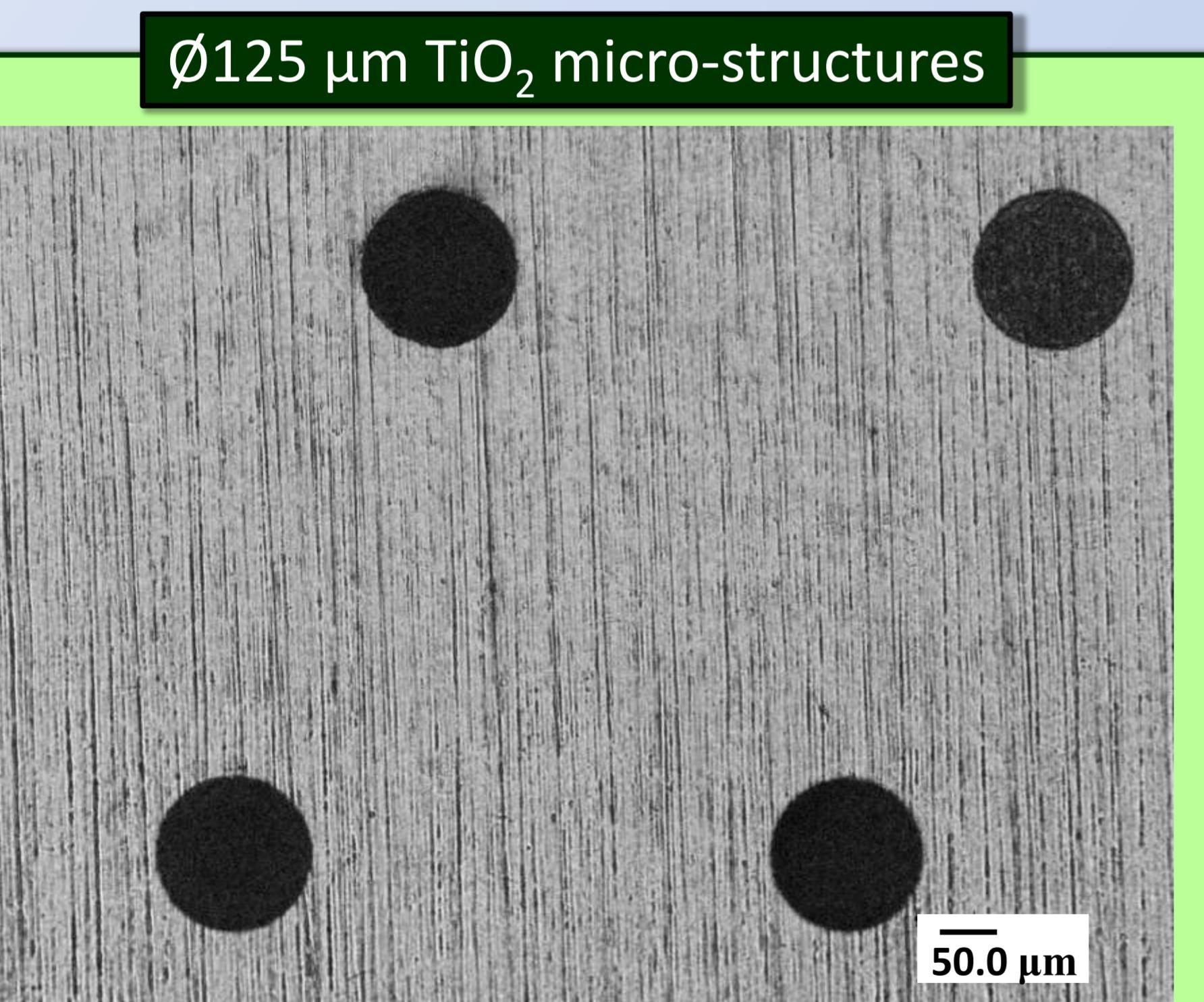
### 5. Cathodic deposition

- 0.47 M NaCl + 25 mM TiCl<sub>3</sub> + 75 mM NaNO<sub>3</sub>
- 25 mA/cm<sup>2</sup> for 5 min
- 25 °C

### 4. Micro-patterns formed after development

- 25 °C for 5 min

## Results and Discussion



- Compact film with micro-scale particles

## Conclusions

- TiO<sub>2</sub> micro-structures were successfully fabricated utilizing lithography and cathodic deposition.
- Diameter of the TiO<sub>2</sub> micro-structures ranged from 50-125 µm

## Reference

- Ma et al., Appl. Phys. Lett. 101 (2012) 141105.
- Meen et al., J. Phys. Chem. Solids, 72 (2011) 653.
- C.C.Huang et al., Electrochim. Acta 55 (2010) 7028.